US1AFL-AT THRU US1MFL-AT

SURFACE ULTRAFAST RECOVERY RECTIFIERS

Forward Current-1A

Reverse Voltage-50V to 1000V

FEATURES

- **♦** For surface mount applications
- ♦ Glass passivated chip junction
- ◆ Low profile package
- ♦ Easy to pick and place
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

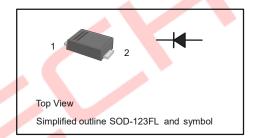
◆ Case: SOD-123FL molded plastic body

◆ Terminals: Solderable per MIL-STD- 750, Method 2026

♦ Weight: Approximated 0.015 grams

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derating by 20 %.

PARAMETER	SYMBOL	US1AFL -AT	US1BFL -AT	US1DFL -AT	US1GFL -AT	US1JFL -AT	US1KFL -AT	US1MFL -AT	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	٧
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	٧
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	٧
Maximum Average Forward Rectified Current at T _C =125°C	I _{F(AV)}	1					Α		
Peak Forward Surge Current(Note1)	I _{FSM}	30					Α		
Maximum Forward Voltage at 1.0 A	VF		1.0		1.3		1.65		٧
Maximum DC Reverse Current at Rated DC Blocking Voltage T _A =25°C T _A =125°C	I _R	5 100					uA		
Maximum Reverse Recovery Time (Note2)	Trr	50 75				nS			
Typical Thermal Resistance (Note3)	Reja	80					°C/W		
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150					°		

Notes: 1. Measured at 8.3 ms single half sine wave superimposed on rated load (JEDEC Method).

2. Measured at with I_F=0.5A, I_{rr}=0.25A.

3. P.C.B. mounted with 2.0" X 2.0" (5cm X 5 cm) copper pad areas.



Dated: 04/2016

Rev:1.0

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RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve Average Forward Current (A) 0.8 0.6 0.4 0.2 Single phase half-wave 60 Hz resistive or inductive load 0.0 100 150 175 Case Temperature (°C)

Fig.3 Typical Forward Characteristics

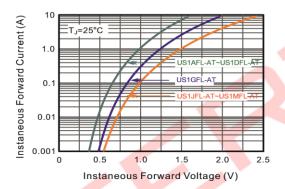


Fig.2 Typical Reverse Characteristics Instaneous Reverse Current (µA) 100 T_J=125°C 10 1.0 0.1 00 percentage of Peak Reverse Voltage (%)

Fig.4 Maximum Non-Repetitive Peak Forward Surge Current 35 Peak Forward Surge Current (A) 30 25 20 15 10 05 8.3 ms Single Half Si (JEDEC Method) 00 10 100 **Number of Cycles**



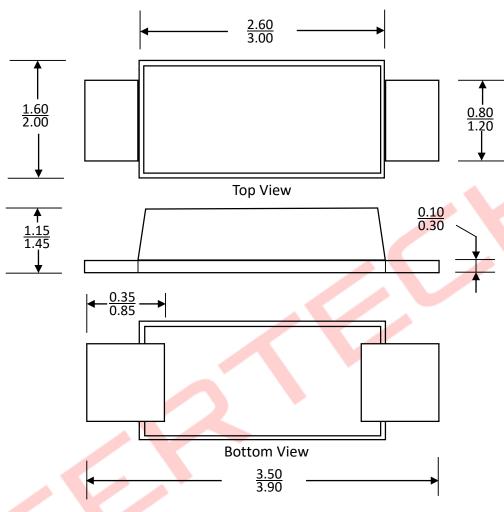
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US1AFL-AT THRU US1MFL-AT

PACKAGE OUTLINE





Dimensions in milimeters

ORDERING INFORMATION

Device	Package	Shipping
US1AFL-AT thru US1MFL-AT	SOD-123FL	3,000/Tape & Reel (7 inches)



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